Integrated Silicon Pressure Sensor On-Chip Signal Conditioned, Temperature Compensated and Calibrated

MPX4250D SERIES

INTEGRATED PRESSURE SENSOR
0 to 250 kPa (0 to 36.3 psi)
0.2 to 4.9 Volts Output

The MPX4250D series piezoresistive transducer is a state–of–the–art monolithic silicon pressure sensor designed for a wide range of applications, particularly those employing a microcontroller or microprocessor with A/D inputs. This transducer combines advanced micromachining techniques, thin–film metallization, and bipolar processing to provide an accurate, high–level analog output signal that is proportional to the applied pressure. The small form factor and high reliability of on–chip integration make the Motorola sensor a logical and economical choice for the automotive system engineer.

Features

- Differential and Gauge Applications Available
- 1.4% Maximum Error Over 0° to 85°C
- Patented Silicon Shear Stress Strain Gauge
- Temperature Compensated Over –40° to +125°C
- Offers Reduction in Weight and Volume Compared to Existing Hybrid Modules
- Durable Epoxy Unibody Element

Applications

- Ideally Suited for Microprocessor or Microcontroller–Based Systems

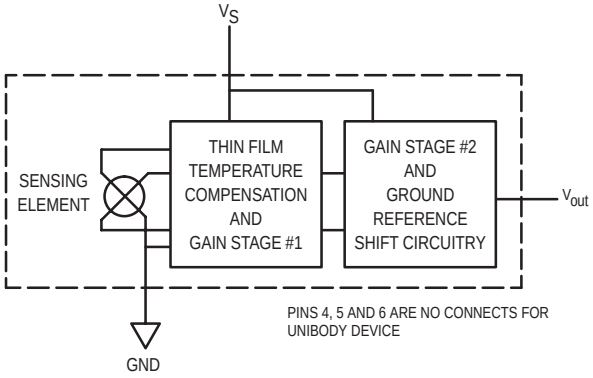
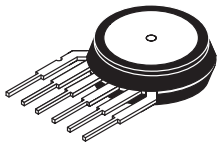
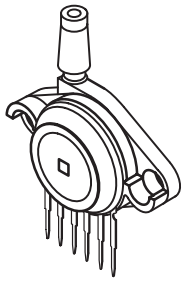


Figure 1. Fully Integrated Pressure Sensor Schematic

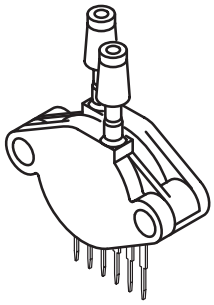
UNIBODY PACKAGE



BASIC CHIP CARRIER ELEMENT CASE 867, STYLE 1



GAUGE PORT OPTION CASE 867B, STYLE 1



DUAL PORT OPTION CASE 867C, STYLE 1

PIN NUMBER			
1	V_{out}	4	N/C
2	Gnd	5	N/C
3	V_S	6	N/C

NOTE: Pins 4, 5, and 6 are internal device connections. Do not connect to external circuitry or ground. Pin 1 is noted by the notch in the lead.

REV 3

MAXIMUM RATINGS(1)

Parametrics	Symbol	Value	Unit
Maximum Pressure(2) (P1 > P2)	P_{max}	1000	kPa
Storage Temperature	T_{stg}	–40° to +125°	°C
Operating Temperature	T_A	–40° to +125°	°C

NOTES:
1. T_C = 25°C unless otherwise noted.
2. Exposure beyond the specified limits may cause permanent damage or degradation to the device.

OPERATING CHARACTERISTICS (V_S = 5.1 Vdc, T_A = 25°C unless otherwise noted, P1 > P2, Decoupling circuit shown in Figure 3 required to meet electrical specifications.)

Characteristic		Symbol	Min	Typ	Max	Unit
Pressure Range(1)		P_{OP}	0	—	250	kPa
Supply Voltage(2)		V_S	4.85	5.1	5.35	Vdc
Supply Current		I_o	—	7.0	10	mAdc
Minimum Pressure Offset(3) @ V_S = 5.1 Volts	(0 to 85°C)	V_{OFF}	0.139	0.204	0.269	Vdc
Full Scale Output(4) @ V_S = 5.1 Volts	(0 to 85°C)	V_{FSO}	4.844	4.909	4.974	Vdc
Full Scale Span(5) @ V_S = 5.1 Volts	(0 to 85°C)	V_{FSS}	—	4.705	—	Vdc
Accuracy(6)	(0 to 85°C)	—	—	—	±1.4	$\%V_{FSS}$
Sensitivity		$\Delta V/\Delta P$	—	18.8	—	mV/kPa
Response Time(7)		t_R	—	1.0	—	msec
Output Source Current at Full Scale Output		I_o+	—	0.1	—	mAdc
Warm–Up Time(8)		—	—	20	—	msec
Offset Stability(9)		—	—	±0.5	—	$\%V_{FSS}$

NOTES:
1. 1.0 kPa (kiloPascal) equals 0.145 psi.
2. Device is ratiometric within this specified excitation range.
3. Offset (V_{off}) is defined as the output voltage at the minimum rated pressure.
4. Full Scale Output (V_{FSO}) is defined as the output voltage at the maximum or full rated pressure.
5. Full Scale Span (V_{FSS}) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum rated pressure.
6. Accuracy (error budget) consists of the following:
   - Linearity: Output deviation from a straight line relationship with pressure over the specified pressure range.
   - Temperature Hysteresis: Output deviation at any temperature within the operating temperature range, after the temperature is cycled to and from the minimum or maximum operating temperature points, with zero differential pressure applied.
   - Pressure Hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from the minimum or maximum rated pressure, at 25°C.
   - TcSpan: Output deviation over the temperature range of 0° to 85°C, relative to 25°C.
   - TcOffset: Output deviation with minimum rated pressure applied, over the temperature range of 0° to 85°C, relative to 25°C.
   - Variation from Nominal: The variation from nominal values, for Offset or Full Scale Span, as a percent of V_{FSS}, at 25°C.
7. Response Time is defined as the time for the incremental change in the output to go from 10% to 90% of its final value when subjected to a specified step change in pressure.
8. Warm–up is defined as the time required for the product to meet the specified output voltage after the Pressure has been stabilized.
9. Offset stability is the product's output deviation when subjected to 1000 hours of Pulsed Pressure, Temperature Cycling with Bias Test.

MECHANICAL CHARACTERISTICS

Characteristics	Typ	Unit
Weight, Basic Element (Case 867)	4.0	Grams

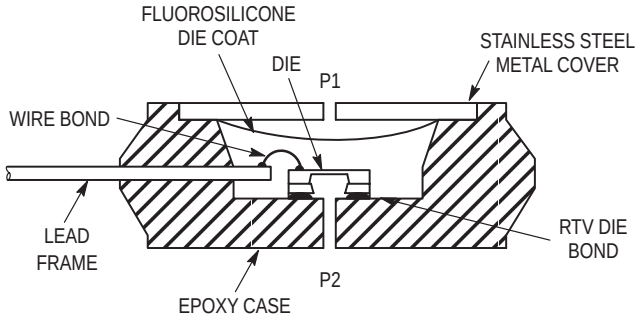


Figure 2. Cross–Sectional Diagram (Not to Scale)

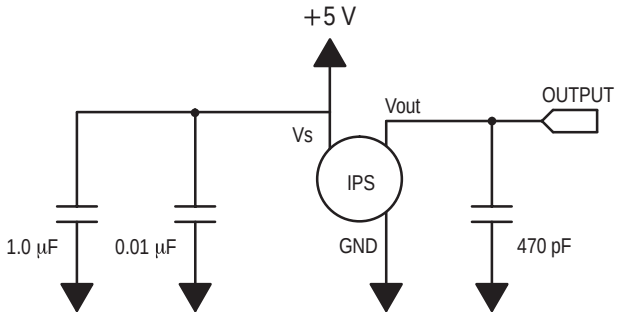


Figure 3. Recommended power supply decoupling and output filtering.
For additional output filtering, please refer to Application Note AN1646.

Figure 2 illustrates the differential/gauge pressure sensing chip in the basic chip carrier (Case 867). A fluorosilicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the sensor diaphragm.

The MPX4250D series pressure sensor operating characteristics and internal reliability and qualification tests are based on use of dry air as the pressure media. Media, other than dry air, may have adverse effects on sensor performance and long–term reliability. Contact the factory for information regarding media compatibility in your application.

Figure 3 shows the recommended decoupling circuit for interfacing the output of the integrated sensor to the A/D input of a microprocessor or microcontroller.

Figure 4 shows the sensor output signal relative to pressure input. Typical, minimum, and maximum output curves are shown for operation over a temperature range of 0° to 85°C using the decoupling circuit shown in Figure 3. The output will saturate outside of the specified pressure range.

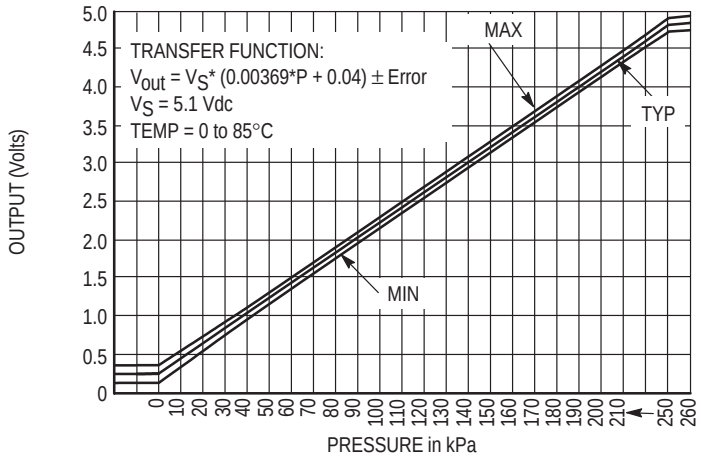
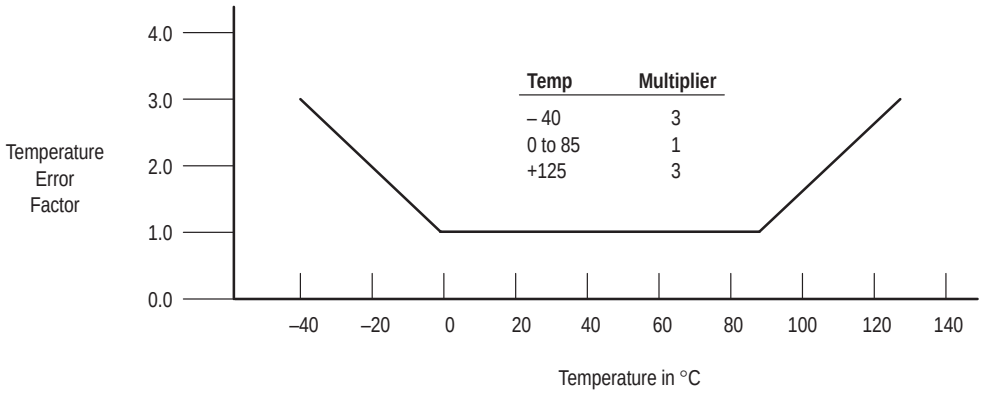


Figure 4. Output versus Differential Pressure

Transfer Function (MPX4250D)

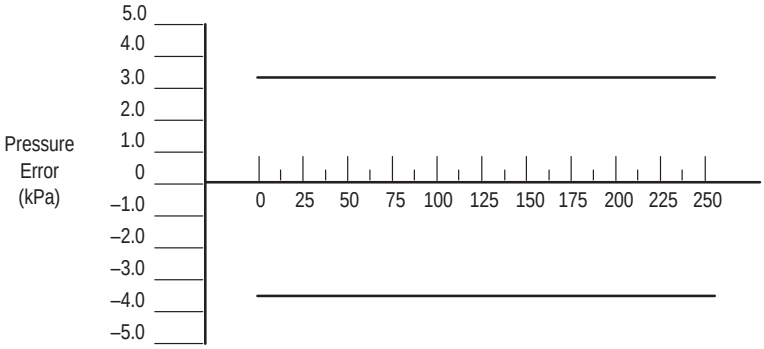
Nominal Transfer Value: $V_{out} = V_S \times (0.00369 \times P + 0.04)$
$\pm$ (Pressure Error x Temp. Factor x 0.00369 x V_S)
$V_S = 5.1 \pm 0.25$ Vdc

Temperature Error Band



NOTE: The Temperature Multiplier is a linear response from 0° to –40°C and from 85° to 125°C.

Pressure Error Band



Pressure	Error (max)
0 to 250 kPa	± 3.45 kPa

ORDERING INFORMATION

The MPX4250D series silicon pressure sensors are available in the basic element package or with pressure port fittings that provide mounting ease and barbed hose connections.

Device Type/Order No.	Options	Case No.	Marking
MPX4250D	Basic Element	867	MPX4250D
MPX4250GP	Gauge Ported Element	867B	MPX4250GP
MPX4250DP	Dual Ported Element	867C	MPX4250DP